

#### 50V N-Channel Enhancement Mode MOSFET - ESD Protected

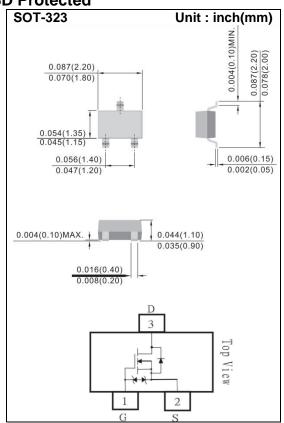
Voltage 50 V Current 360mA

#### **Features**

- RDS(ON), VGS@10V, ID@500mA<1.6Ω
- RDS(ON), VGS@4.5V, ID@200mA<2.5Ω</li>
- RDS(ON), VGS@2.5V, ID@100mA<4.5Ω</li>
- Advanced Trench Process Technology
- Specially Designed for Battery Operated Systems, Solid-State Relays Drivers: Relay, Displays, Memories, etc.
- ESD Protected 2KV HBM
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Green molding compound as per IEC61249 Std. (Halogen Free)

#### **Mechanical Data**

- Case: SOT-323 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.00018 ounces, 0.005 grams



### **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	50	V
Gate-Source Voltage		V <sub>G</sub> s	<u>+</u> 20	V
Continuous Drain Current		I <sub>D</sub>	360	mA
Pulsed Drain Current		I <sub>DM</sub>	1200	mA
Power Dissipation	T <sub>A</sub> =25°C		236	mW
	Derate above 25°C	P <sub>D</sub>	1.89	mW/°C
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~150	۰C
Typical Thermal resistance - Junction to Ambient (Note 3)		RөJA	530	°C/W



## Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub> V <sub>GS</sub> =0V,I <sub>D</sub> =250uA		50	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	0.8	1.0	1.5	V	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V,I <sub>D</sub> =500mA	-	0.96	1.6	Ω	
		V <sub>GS</sub> =4.5V,I <sub>D</sub> =200mA	-	1.25	2.5		
		V <sub>GS</sub> =2.5V,I <sub>D</sub> =100mA	-	2.73	4.5		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =50V,V <sub>GS</sub> =0V	-	0.01	1	uA	
Gate-Source Leakage Current	Igss	V <sub>GS</sub> = <u>+</u> 20V,V <sub>DS</sub> =0V	-	<u>+</u> 3.0	<u>+</u> 10	uA	
Dynamic							
Total Gate Charge	$Q_g$	\/ 05\/ L 050 A	-	0.63	1	nC	
Gate-Source Charge	$Q_gs$	V <sub>DS</sub> =25V, I <sub>D</sub> =250mA,	-	0.2	-		
Gate-Drain Charge	$Q_gd$	VGS=4.5V (Note 1,2)	-	0.23	-		
Input Capacitance	Ciss	\\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	-	25	50	pF	
Output Capacitance	Coss	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V,	-	9.5	20		
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	2.1	5		
Switching							
Turn-On Delay Time	td <sub>(on)</sub>	)/ O5)/ L 500 A	-	2.2	5	ns	
Turn-On Rise Time	tr	V <sub>DD</sub> =25V, I <sub>D</sub> =500mA,		19.2	38		
Turn-Off Delay Time	td <sub>(off)</sub>	$V_{GS}=10V$ , $R_{G}=6\Omega$ (Note 1,2)		6.2	12		
Turn-Off Fall Time	tf	RG=012 (Note 1,2)	-	23	50		
Drain-Source Diode							
Maximum Continuous Drain-Source Diode Forward Current	Is		-	-	500	mA	
Diode Forward Voltage	V <sub>SD</sub>	Is=500mA, V <sub>GS</sub> =0V		0.86	1.5	V	

#### NOTES:

- 1. Pulse width<300μs, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejua is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. mounted on a 1 inch square pad of copper



#### **TYPICAL CHARACTERISTIC CURVES**

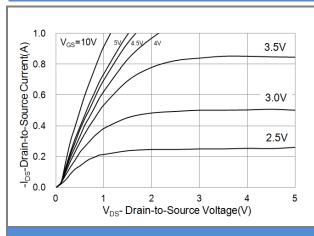
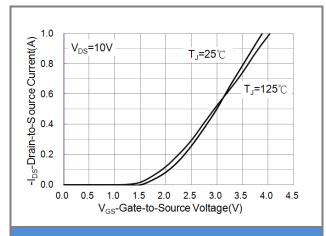


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

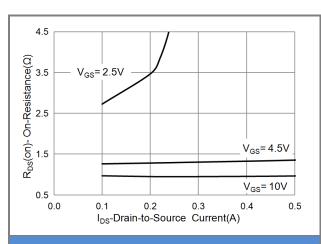


Fig.3 On-Resistance vs. Drain Current

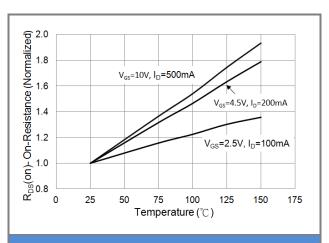


Fig.4 On-Resistance vs. Junction temperature

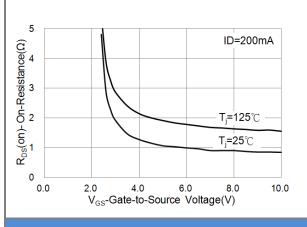


Fig.5 On-Resistance Variation with VGS.

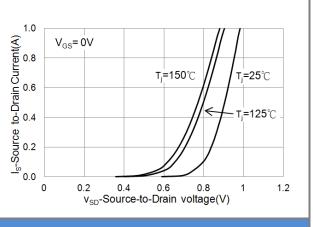


Fig.6 Body Dlode CharacterIslcs



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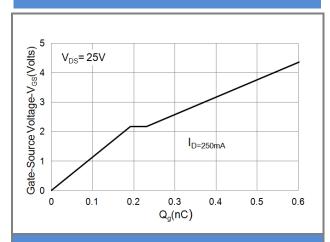


Fig.7 Gate-Charge Characteristics

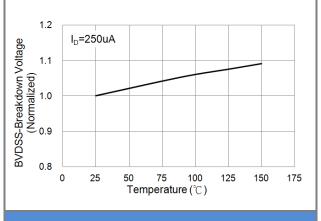


Fig.8 Breakdown Voltage Variation vs. Temperature

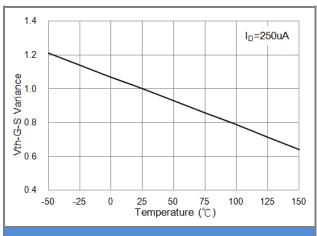


Fig.9 Threshold Voltage Variation with Temperature.

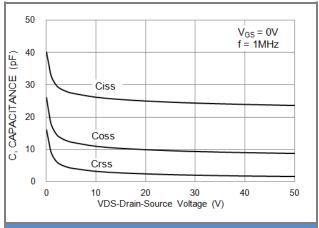


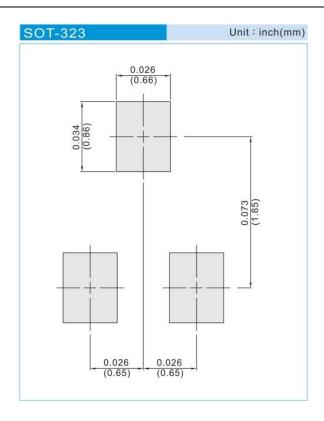
Fig.10 Capacitance vs. Drain-Source Voltage.



## **Product and Packing Information**

Part No.	Package Type	/pe Packing Type Ma	
PJC138K	SOT-323	3K pcs / 7" reel	8KW
PJC138K	SOT-323	12K pcs / 13" reel	8KW

## **Mounting Pad Layout**





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